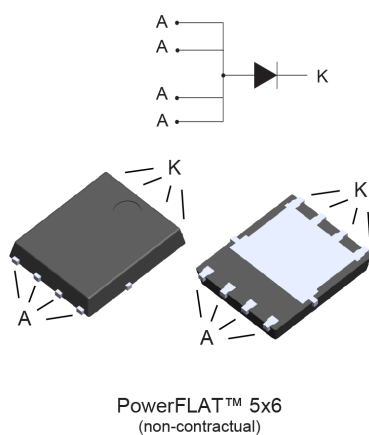


100 V, 30 A field effect rectifier



Features

- ST patented rectifier process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation
- ECOPACK®2 compliant

Applications

- Switching diode
- Notebook adapter
- LED lighting
- DC / DC converter

Description

The FERD30SM100DJF is based on a proprietary technology that achieves the best in class V_F / I_R trade-off for a given silicon surface.

Packaged in PowerFLAT™ 5x6, the FERD30SM100DJF is optimized for use in confined applications where both efficiency and thermal performance are key.

Product status	
FERD30SM100DJF	
Product summary	
Symbol	Value
$I_{F(AV)}$	30 A
V_{RRM}	100 V
$T_{j(max.)}$	175 °C
$V_{F(typ.)}$	0.665 V

1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals short circuited)

Symbol	Parameter	Value	Unit
V _{RRM}	Repetitive peak reverse voltage	100	V
I _{F(RMS)}	Forward rms current	45	A
I _{F(AV)}	Average forward current, $\delta = 0.5$, square wave	T _C = 100 °C 30	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal 180	A
T _{stg}	Storage temperature range	-65 to +175	°C
T _J	Maximum operating junction temperature ⁽¹⁾	+175	°C

1. $(dP_{tot}/dT_J) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameter

Symbol	Parameter	Max. value	Unit
R _{th(j-c)}	Junction to case	2.6	°C/W

For more information, please refer to the following application note :

- AN5046 : Printed circuit board assembly recommendations for STMicroelectronics PowerFLAT™ packages

Table 3. Static electrical characteristics (anode terminals short-circuited)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _J = 25 °C	-	-	150	μA
		T _J = 125 °C	-	8	16	mA
		T _J = 125 °C	-	-	9	
V _F ⁽²⁾	Forward voltage drop	T _J = 25 °C	-	-	0.480	V
		T _J = 125 °C	-	0.395	0.435	
		T _J = 25 °C	-	-	0.595	
		T _J = 125 °C	-	0.510	0.555	
		T _J = 25 °C	-	-	0.970	
		T _J = 125 °C	-	0.665	0.735	

1. Pulse test: t_p = 5 ms, $\delta < 2\%$

2. Pulse test: t_p = 380 μs, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.562 \times I_{F(AV)} + 0.0057 \times I_{F(RMS)}^2$$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (anode terminals short circuited)

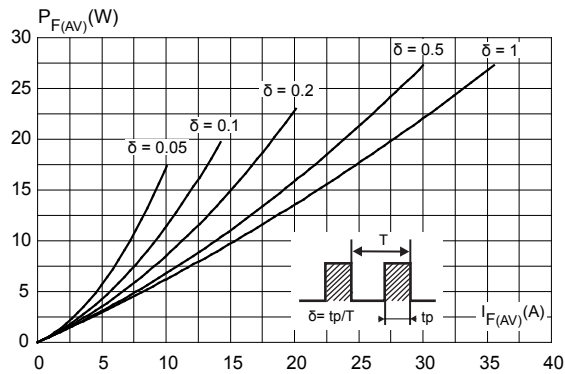


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, anode terminals short circuited)

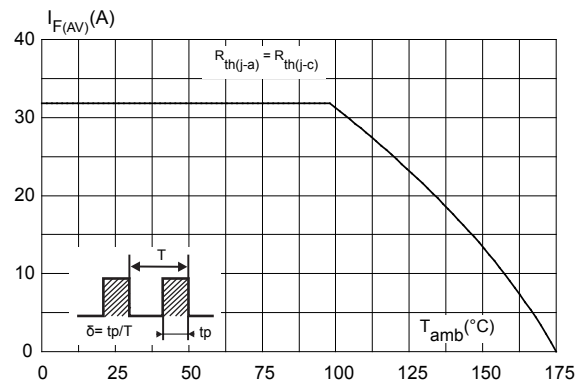


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

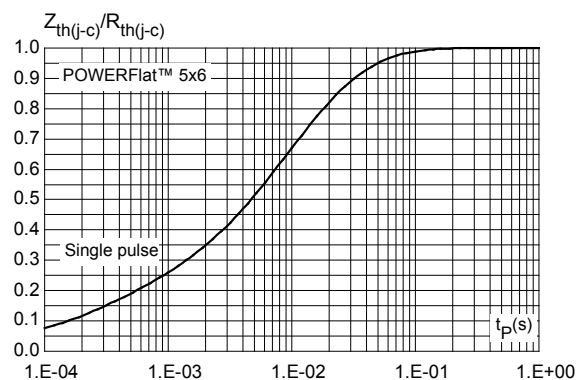


Figure 4. Reverse leakage current versus reverse voltage applied (typical values)

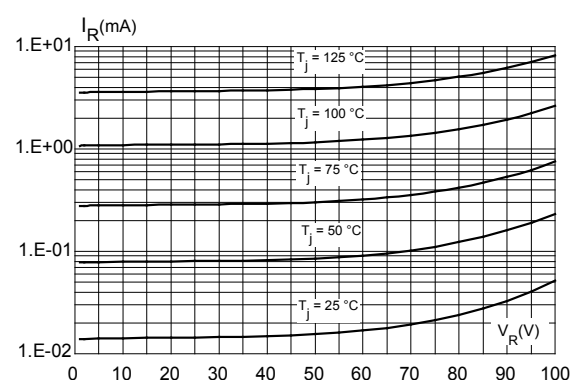


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

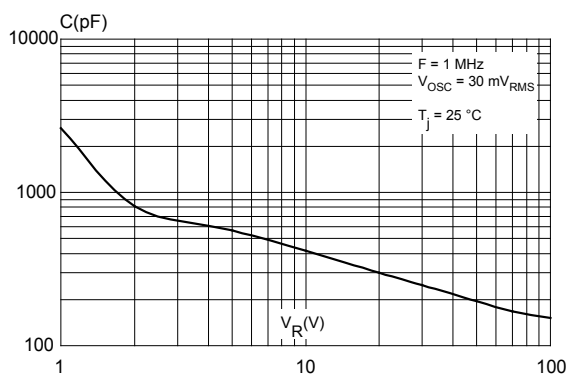


Figure 6. Forward voltage drop versus forward current (typical values, anode terminals short circuited)

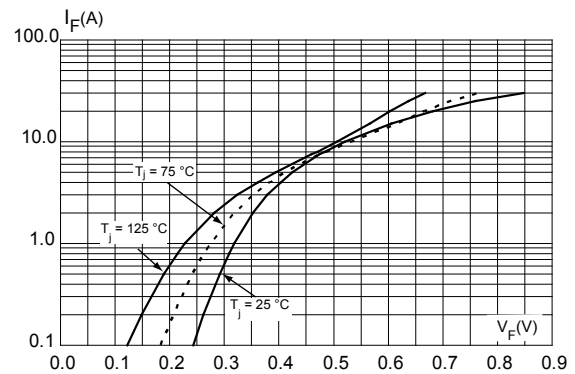
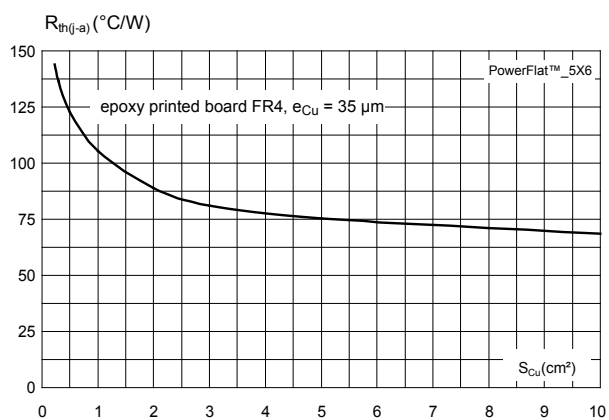


Figure 7. Thermal resistance junction to ambient versus copper surface under tab (typical values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK®** packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 PowerFLAT™ 5x6 package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)

Figure 8. PowerFLAT™ 5x6 package outline (non-contractual)

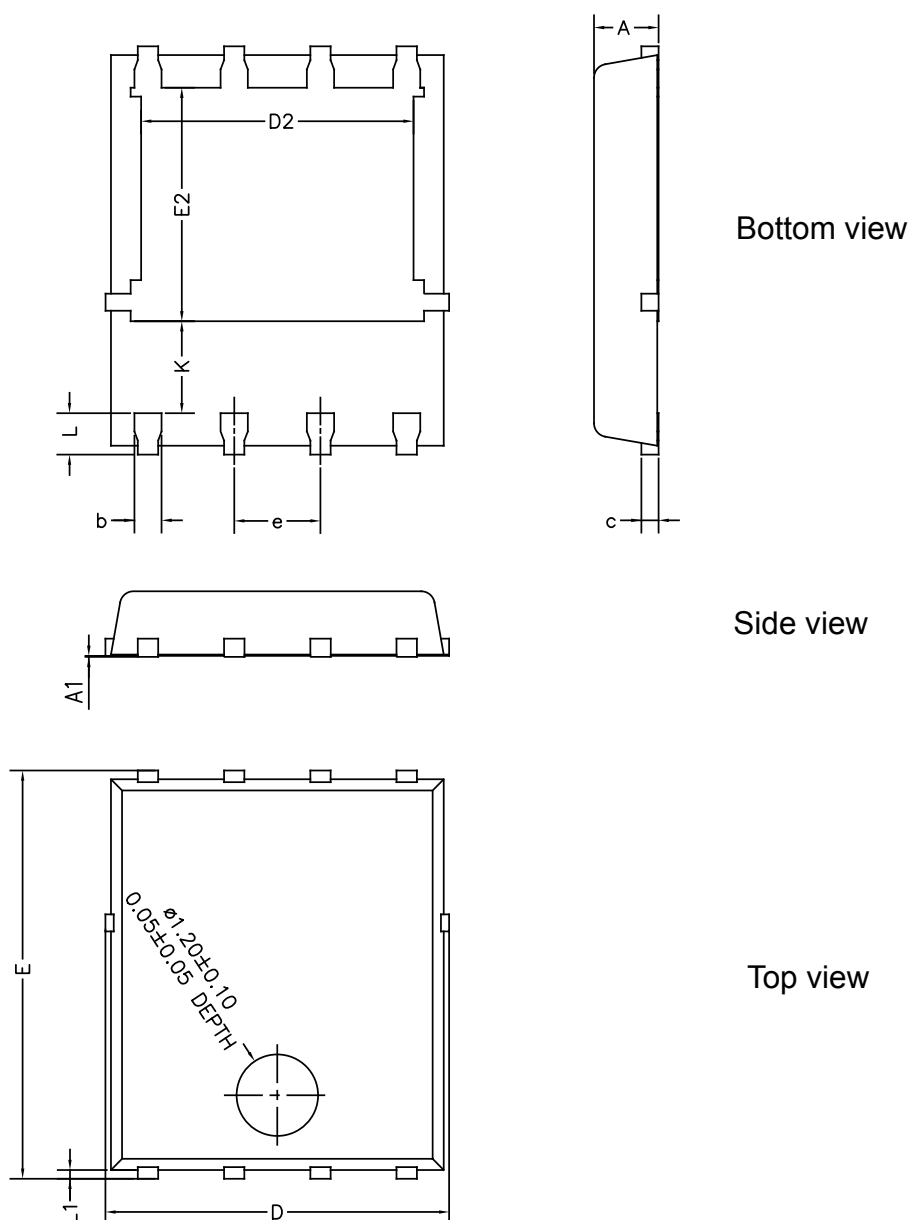
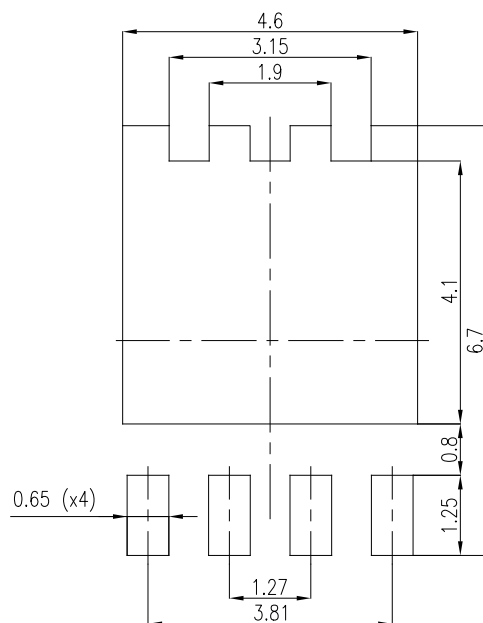


Table 4. PowerFLAT™ 5x6 mechanical data

Ref	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.80		1.00	0.031		0.039
A1	0.00		0.05	0.000		0.002
b	0.30		0.50	0.01		0.02
c		0.25			0.010	
D	4.80		5.40	0.189		0.212
D2	3.91		4.45	0.154		0.175
e		1.27			0.050	
E	5.90		6.35	0.232		0.250
E2	3.34		3.70	0.138		0.146
L	0.50		0.80	0.020		0.031
K	1.10		1.575	0.015		0.023
L1	0.05	0.15	0.25	0.002	0.006	0.009

Figure 9. PowerFLAT™ 5x6 recommended footprint (dimensions are in mm)


3 Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
FERD30SM100DJFTR	F30SM 100	PowerFLAT™ 5x6	95 mg	3000	Tape and reel

Revision history

Table 6. Document revision history

Date	Version	Changes
09-Jan-2015	1	Initial release.
29-Nov-2018	2	Updated Section Cover image and Section 2.1 PowerFLAT™ 5x6 package information . Added Section Applications .
08-Feb-2019	3	Updated Figure 8. PowerFLAT™ 5x6 package outline (non-contractual) and Table 4. PowerFLAT™ 5x6 mechanical data .

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